TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74VHC138F, TC74VHC138FN, TC74VHC138FT

3-TO-8 LINE DECODER

The TC74VHC138 is an advanced high speed CMOS 3-to-8 DECODER fabricated with silicon gate C2MOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

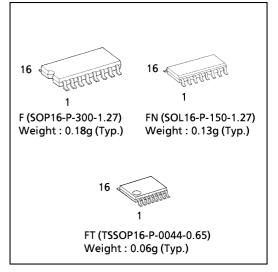
When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs $(\overline{Y}0 - \overline{Y}7)$ will go low.

When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high. G1, $\overline{G}2A$, and $\overline{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems. An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES:

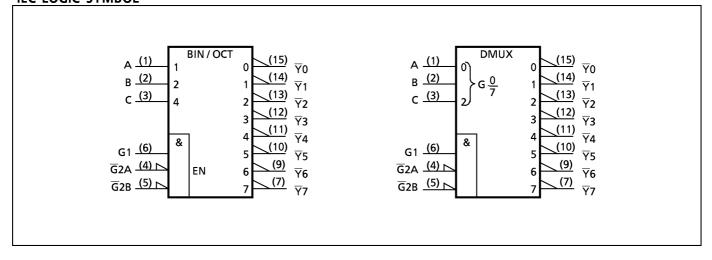
- High Speed------t_{pd} = 5.7ns(typ.) at V_{CC} = 5V
- Low Power Dissipation $I_{CC} = 4\mu A(Max.)$ at Ta = 25°C
- High Noise Immunity $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays ····· t_{pLH} ≃ t_{pHL}
- Wide Operating Voltage Range ···· V_{CC} (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74ALS138

(Note) The JEDEC SOP (FN) is not available in Japan.



PIN ASSIGNMENT V_{CC} Α 16 $\overline{Y}0$ В 2 15 $\overline{Y}1$ C 3 14 **G**2A 4 <u>7</u>2 13 $\overline{G}2B$ 5 12 74 G1 **⊽**7 7 10 **Y**5 8 9 **∀**6 **GND** VIEW) (TOP

IEC LOGIC SYMBOL



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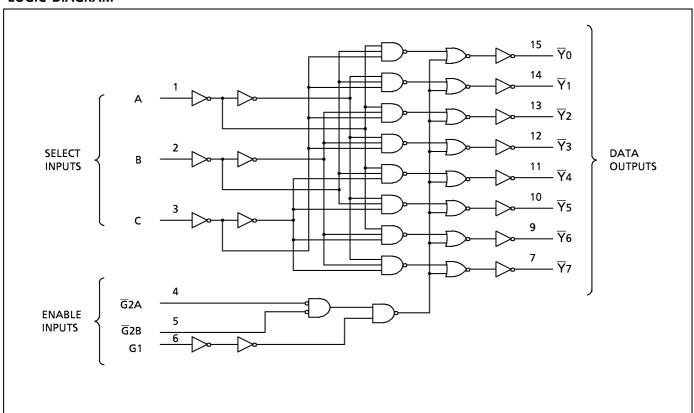
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TRUTH TABLE

	INPUTS						OUTPUTS									
E	ENABLE			SELECT		₹0	<u></u> 71	_ ₹2		<u>¥</u> 4	∀ 5		<u>7</u> 7	SELECTED OUTPUT		
G1	G2A	G ₂ B	C	В	Α	'0		12	'3	14	13		' /			
L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	NONE		
Х	Н	Х	Χ	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	NONE		
Х	Х	Н	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	NONE		
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	₹0		
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	<u></u> 71		
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	₹2		
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	<u>¥</u> 3		
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	<u>¥</u> 4		
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	₹ 5		
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	<u></u> ∀6		
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	<u>\(\bar{Y} \) </u>		

X : Don't Care

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{cc}	-0.5~7.0	٧
DC Input Voltage	V _{IN}	-0.5~7.0	V
DC Output Voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	٧
Input Diode Current	I _{IK}	-20	mA
Output Diode Current	I _{OK}	± 20	mA
DC Output Current	I _{OUT}	± 25	mA
DC V _{CC} /Ground Current	I _{cc}	± 75	mA
Power Dissipation	P _D	180	mW
Storage Temperature	T _{stg}	−65~150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V _{cc}	2.0~5.5	>
Input Voltage	VIN	0~5.5	٧
Output Voltage	V _{OUT}	0~V _{cc}	٧
Operating Temperature	T _{opr}	−40~85	°C
Input Rise and Fall Time	dt/dv	$0\sim100 \ (V_{CC} = 3.3 \pm 0.3 V)$ $0\sim20 \ (V_{CC} = 5 \pm 0.5 V)$	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CO	V _{cc}	Ta = 25°C			Ta = - 4	10~85°C	UNIT	
PARAIVIETER	STIVIBUL	1 1 1 1 1 1	(V)	MIN.	TYP.	MAX.	MIN.	MAX.	CIVIT	
High - Level	.,			2.0 3.0~ 5.5	1.50	_	_	1.50	_	
Input Voltage	V _{IH}				$V_{cc} \times 0.7$	_	_	$V_{cc} \times 0.7$	-	
Low - Level			2.0	_	-	0.50	_	0.50	V	
Input Voltage	V _{IL}		3.0~ 5.5	_	_	$V_{cc} \times 0.3$	_	$V_{cc} \times 0.3$		
	V _{OH}	.,	$I_{OH} = -50 \mu A$	2.0	1.9	2.0	_	1.9		V
High - Level Output Voltage		$V_{IN} = V_{IH} \text{ or } V_{IL}$		3.0 4.5	2.9 4.4	3.0 4.5	_	2.9 4.4	_	
			$I_{OH} = -4mA$ $I_{OH} = -8mA$	3.0 4.5	2.58 3.94	_	_	2.48 3.80		
Low - Level Output Voltage	V _{OL}	V _{1 N} =	I _{OL} = 50μA	2.0 3.0 4.5	_ _ _	0.0 0.0 0.0	0.1 0.1 0.1	_ _ _	0.1 0.1 0.1	V
		V _{IH} or V _{IL}	$I_{OL} = 4mA$ $I_{OL} = 8mA$	3.0 4.5	_	_	0.36 0.36	_	0.44 0.44	
Input Leakage Current	I _{IN}	$V_{IN} = 5.5V$ or GND		0~5.5	_		± 0.1	_	± 1.0	Λ
Quiescent Supply Current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	_	40.0	μ A

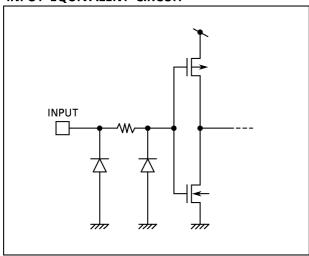
PARAMETER	SYMBOL	TEST	T CONDITION		Ta = 25°C			Ta = - 4	UNIT	
PARAIVIETER	STIVIBUL		V _{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	OIVIII
B			3.3 ± 0.3	15	_	8.2	11.4	1.0	13.5	ns
Propagation Delay Time	t _{pLH} t _{pHL}			50	_	10.0	15.8	1.0	18.0	
(A, B, C-₹)			5.0 ± 0.5	15	_	5.7	8.1	1.0	9.5	
				50	_	7.2	10.1	1.0	11.5	
B	t _{pLH} t _{pHL}		3.3 ± 0.3	15	_	8.1	12.8	1.0	15.0	
Propagation Delay Time				50	_	10.6	16.3	1.0	18.5	
(G1-Ÿ)			5.0 ± 0.5	15	_	5.6	8.1	1.0	9.5	
				50	_	7.1	10.1	1.0	11.5	
Barrier Balan Elan		t _{pLH} t _{pHL}	3.3 ± 0.3	15	_	8.2	11.4	1.0	13.5	
Propagation Delay Time	t _{pLH} t _{pHL}			50	_	10.7	14.9	1.0	17.0	
(G 2 - Y)			5.0 ± 0.5	15	_	5.8	8.1	1.0	9.5	
				50	_	7.3	10.1	1.0	11.5	
Input Capacitance	C _{I N}				_	4	10	_	10	pF
Power Dissipation Capacitance	C _{PD}	(Note 1)			_	34	_	_	_	Pr

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

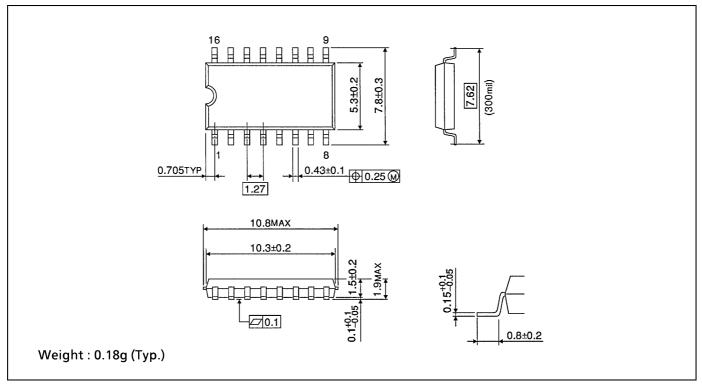
$$I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

INPUT EQUIVALENT CIRCUIT



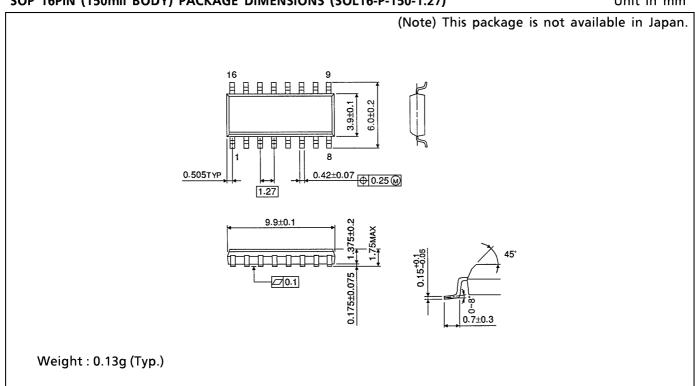
SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm



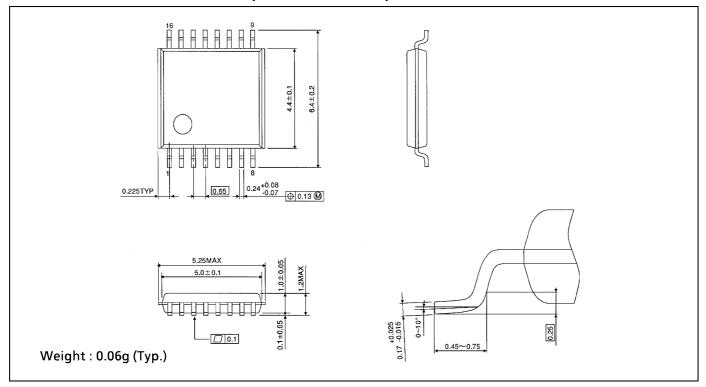
SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150-1.27)

Unit in mm



TSSOP 16PIN PACKAGE DIMENSIONS (TSSOP16-P-0044-0.65)

Unit in mm



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